## NSN 5961-01-378-8090

No Fiig: A110a0



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-378-8090 **Inclosure Material:** Metal **Overall Length:** 1.000 inches **Overall Diameter:** Between 0.240 inches and 0.280 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.687 inches Thready Qty Per Inch (tpi): 28 **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage and 600.0 emitter to collector voltage, floating potential, dc with base biased in reverse direction with respect to the collector **Current Rating Per Characteristic:** 85.00 amperes all primaries preset **Maximum Operating Tempurature Per Measurement Point:** 180.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: